COMPLIANT

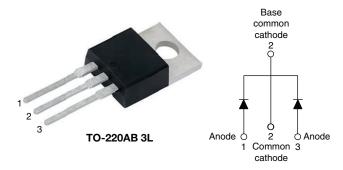
FREE



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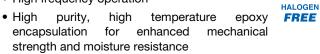
High Performance Schottky Rectifier, 2 x 30 A



PRIMARY CHARACTERISTICS								
I _{F(AV)}	2 x 30 A							
V _R	100 V							
V _F at I _F	0.69 V							
I _{RM} max.	20 mA at 125 °C							
T _J max.	175 °C							
E _{AS}	11.25 mJ							
Package	3L TO-220AB							
Circuit configuration	Common cathode							

FEATURES

- 175 °C T_{.I} operation
- · Low forward voltage drop
- High frequency operation



- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	VALUES	UNITS						
I _{F(AV)}	Rectangular waveform (per device)	60	Α					
V _{RRM}		100	V					
I _{FRM}	T _C = 139 °C (per leg)	60	۸					
I _{FSM}	t _p = 5 μs sine	1500	A					
V _F	30 A _{pk} , T _J = 125 °C	0.69	V					
T _J	Range	-65 to +175	°C					

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-63CTQ100-M3	UNITS					
Maximum DC reverse voltage	V_R	100	V					
Maximum working peak reverse voltage	V_{RWM}	100	V					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS				
Maximum average forward per leg		50 % duty ovolo at T ₋ = 130 °C	rootongular wayoform	30				
current per device	I _{F(AV)}	50 % duty cycle at T_C = 139 °C, rectangular waveform		60				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 140 °C		60	Α			
Maximum peak one cycle non-repetitive		5 μs sine or 3 μs rect. pulse	Following any rated load	1500				
surge current per leg	I _{FSM}	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	300				
Non-repetitive avalanche energy per leg	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 0.75 \text{A}, L = 40 \text{mH}$		11.25	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		0.75	Α			



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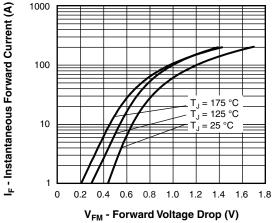
ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS			UNITS			
		30 A	T _{.1} = 25 °C	0.78	0.82				
Maximum forward voltage drop	V _{FM} ⁽¹⁾	60 A	1j=25 C	0.94	1.0	V			
Maximum forward voltage drop		30 A	T _{.1} = 125 °C	0.64	0.69				
		60 A	1J = 125 C	0.78	0.83				
Maximum instantaneous reverse current	I _{RM}	T _J = 25 °C	Rated DC voltage	0.02	0.3	mA			
Maximum instantaneous reverse current		T _J = 125 °C	hated DC voltage	11	20	IIIA			
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range 100 kHz to 1 MHz) 25 °C		1100		pF			
Typical series inductance	L _S	Measured from top of term	8	.0	nH				
Maximum voltage rate of change	dV/dt	Rated V _R	10	000	V/µs				

Note

 $^{^{(1)}\,}$ Pulse width < 300 µs, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		-65 to +175	°C				
Maximum thermal resistance, junction to case per leg	R _{thJC}	DC operation	1.2	°C/W				
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased	0.50	C/VV				
Approximate weight			2	g				
Approximate weight			0.07	OZ.				
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf · cm				
Mounting torque — maximum		Non-lubricated tirreads	12 (10)	(lbf \cdot in)				
Marking device		Case style 3L TO-220AB	63CT	Q100				







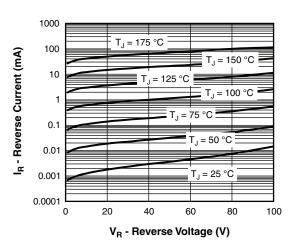


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

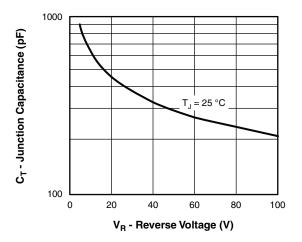


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

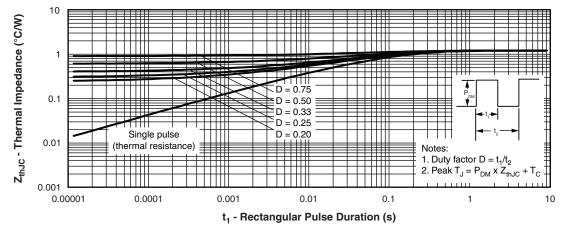


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

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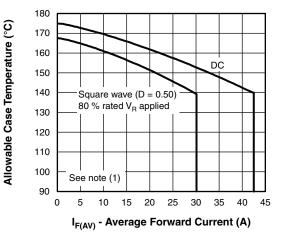


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

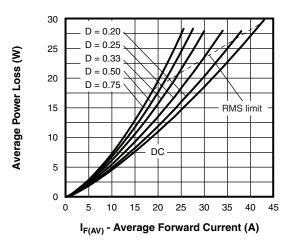


Fig. 6 - Forward Power Loss Characteristics

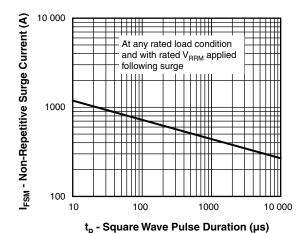


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

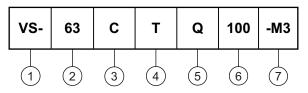
 $^{(2)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{thJC}; Pd = forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R



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ORDERING INFORMATION TABLE





- 1 Vishay Semiconductors product
- 2 Current rating (60 A)
- 3 Circuit configuration

C = common cathode

4 - Package

T = TO-220

- 5 Schottky "Q" series
- 6 Voltage rating (100 = 100 V)
- 7 Environmental digit

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION									
VS-63CTQ100-M3	50	Antistatic plastic tubes							

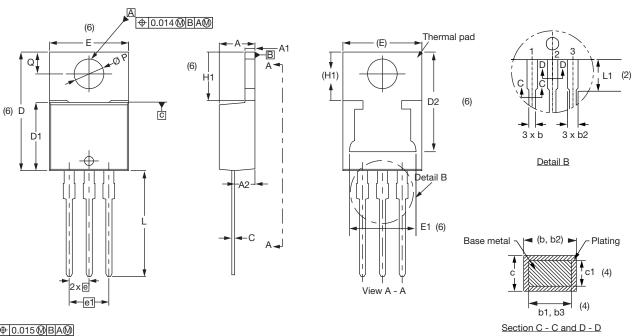
LINKS TO RELATED DOCUMENTS							
Dimensions	www.vishay.com/doc?96154						
Part marking information	www.vishay.com/doc?95028						



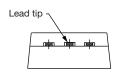
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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIM	IETERS	INC	HES	NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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